

10V Drive Nch MOSFET

R6020ANJ

●Structure

Silicon N-channel MOSFET

●Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Gate-source voltage (V_{GS}) guaranteed to be $\pm 30V$.
- 4) Drive circuits can be simple.
- 5) Parallel use is easy.

●Applications

Switching

●Packaging specifications

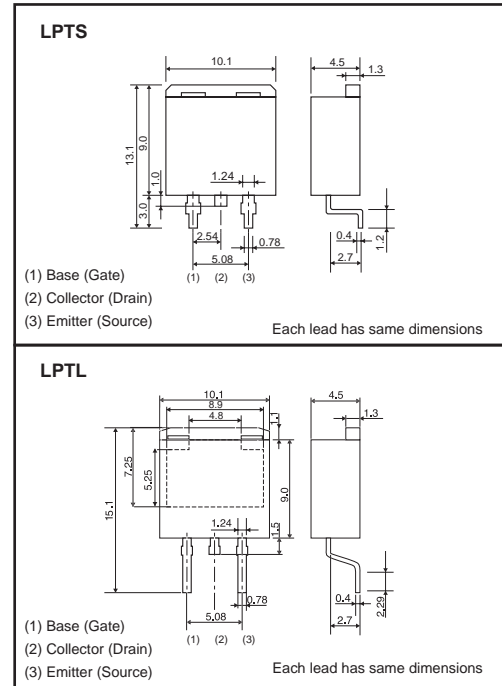
<LPTS>

Type	Package	Taping
	Code	TL
	Basic ordering unit (pieces)	1000
R6020ANJ		○

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Type	Package	Taping
	Code	TLL
	Basic ordering unit (pieces)	1000
R6020ANJ		○

●Dimensions (Unit : mm)

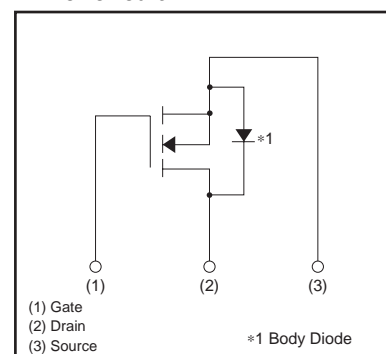


●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit	
Drain-source voltage	V_{DSS}	600	V	
Gate-source voltage	V_{GS}	± 30	V	
Drain current	Continuous	I_D *3	± 20	A
	Pulsed	I_{DP} *1	± 80	A
Source current (Body Diode)	Continuous	I_S *3	20	A
	Pulsed	I_{SP} *1	80	A
Avalanche Current	I_{AS} *2	10	A	
Avalanche Energy	E_{AS} *2	26.7	mJ	
Total power dissipation (Tc=25°C)	P_D	100	W	
Channel temperature	T_{ch}	150	°C	
Range of storage temperature	T_{stg}	-55 to +150	°C	

*1 $P_w \leq 10\mu s$, Duty cycle $\leq 1\%$
 *2 $L = 500\mu H$, $V_{DD} = 50V$, $R_G = 25\Omega$, Starting, $T_{ch} = 25^\circ C$
 *3 Limited only by maximum temperature allowed

●Inner circuit



●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to case	$R_{th(ch-c)}$	1.25	°C/W

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	–	–	±100	nA	$V_{GS}=\pm 30V, V_{DS}=0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	600	–	–	V	$I_D=1mA, V_{GS}=0V$
Zero gate voltage drain current	I_{DSS}	–	–	100	μA	$V_{DS}=600V, V_{GS}=0V$
Gate threshold voltage	$V_{GS(th)}$	2.5	–	4.5	V	$V_{DS}=10V, I_D=1mA$
Static drain-source on-state resistance	$R_{DS(on)}^*$	–	0.19	0.25	Ω	$I_D=10A, V_{GS}=10V$
Forward transfer admittance	$ Y_{fs} ^*$	7	–	–	S	$I_D=10A, V_{DS}=10V$
Input capacitance	C_{iss}	–	2040	–	pF	$V_{DS}=25V$
Output capacitance	C_{oss}	–	1660	–	pF	$V_{GS}=0V$
Reverse transfer capacitance	C_{rss}	–	70	–	pF	$f=1MHz$
Turn-on delay time	$t_{d(on)}^*$	–	40	–	ns	$I_D=10A, V_{DD}\approx 300V$
Rise time	t_r^*	–	60	–	ns	$V_{GS}=10V$
Turn-off delay time	$t_{d(off)}^*$	–	230	–	ns	$R_L=30\Omega$
Fall time	t_f^*	–	70	–	ns	$R_G=10\Omega$
Total gate charge	Q_g^*	–	65	–	nC	$V_{DD}\approx 300V$
Gate-source charge	Q_{gs}^*	–	10	–	nC	$I_D=20A$ $V_{GS}=10V$
Gate-drain charge	Q_{gd}^*	–	25	–	nC	$R_L=15\Omega / R_G=10\Omega$

* Pulsed

●Body diode characteristics (Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V_{SD}^*	–	–	1.5	V	$I_S=10A, V_{GS}=0V$

* Pulsed

●Electrical characteristics curves

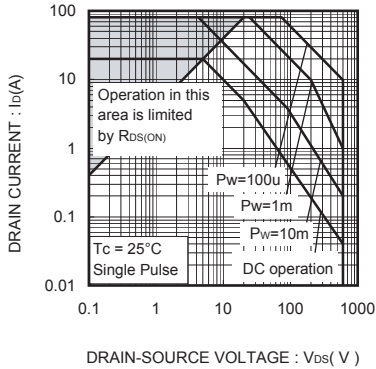


Fig.1 Maximum Safe Operating Area

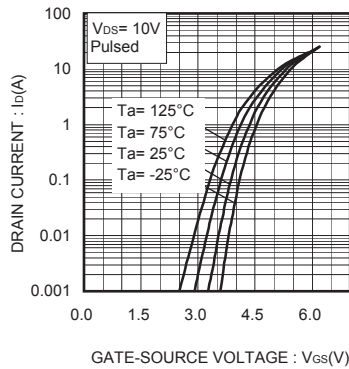


Fig.2 Typical Transfer Characteristics

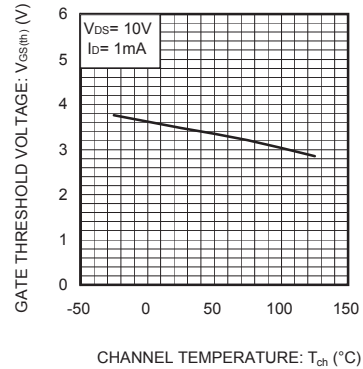


Fig.3 Gate Threshold Voltage vs. Channel Temperature

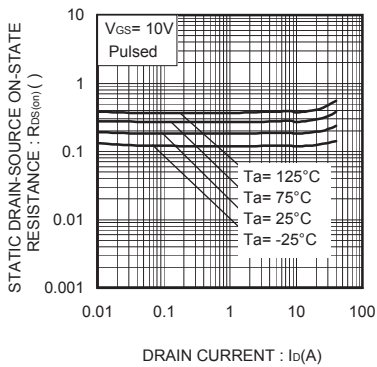


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current

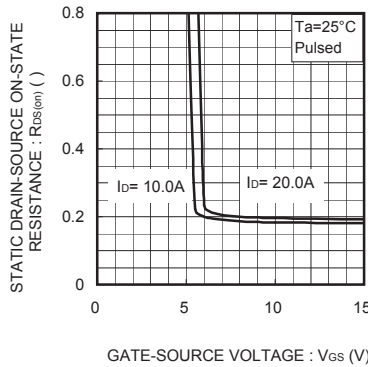


Fig.5 Static Drain-Source On-State Resistance vs. Gate Source

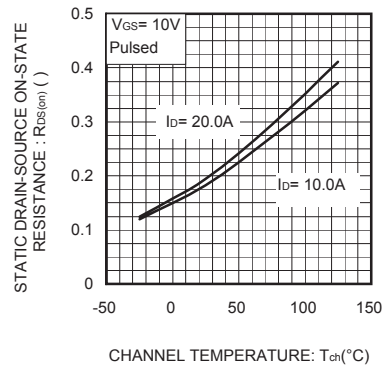


Fig.6 Static Drain-Source On-State Resistance vs. Channel Temperature

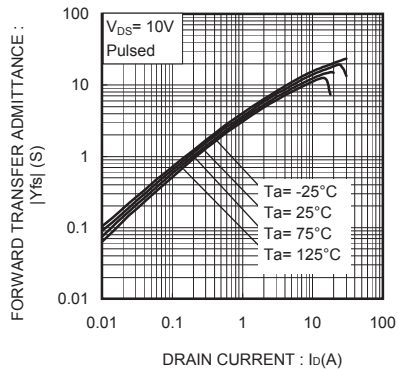


Fig.7 Forward Transfer Admittance vs. Drain Current

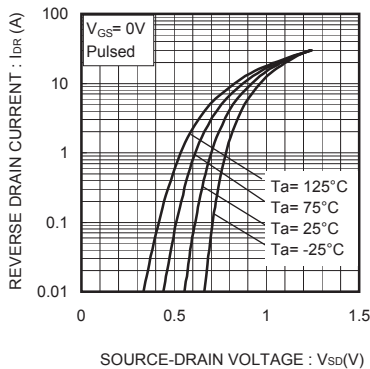


Fig.8 Reverse Drain Current vs. Source-Drain Voltage

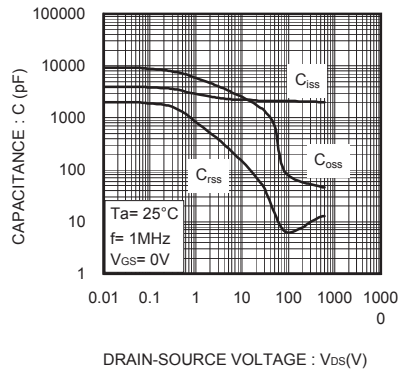
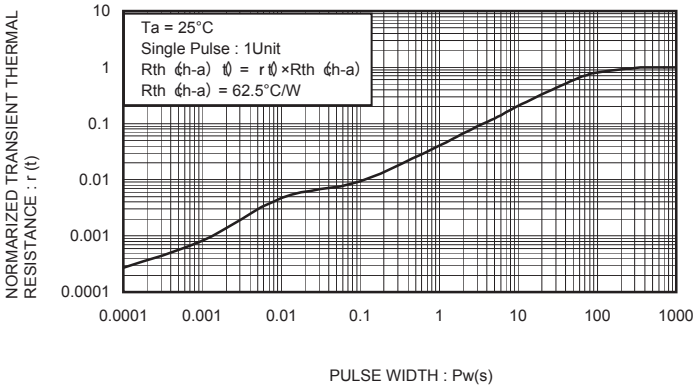
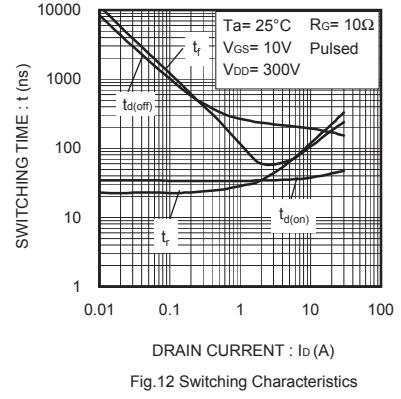
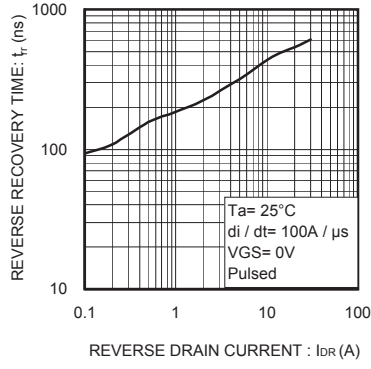
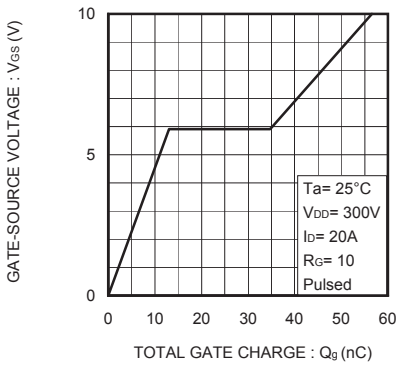


Fig.9 Typical Capacitance vs. Drain-Source Voltage



●Measurement circuits

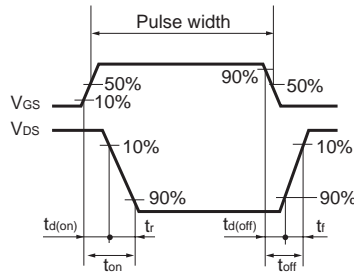
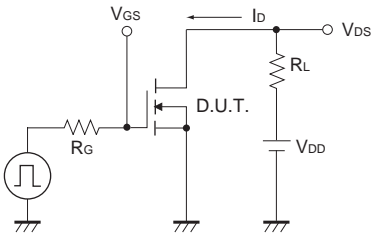


Fig.1-1 Switching time measurement circuit

Fig.1-2 Switching waveforms

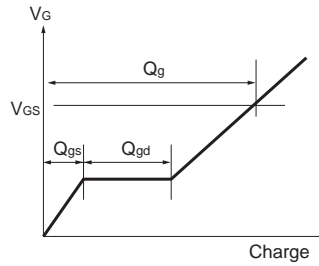
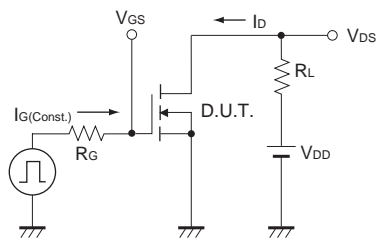


Fig.2-1 Gate charge measurement circuit

Fig.2-2 Gate charge waveform

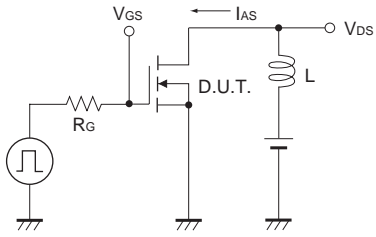


Fig.3-1 Avalanche Measurement circuit

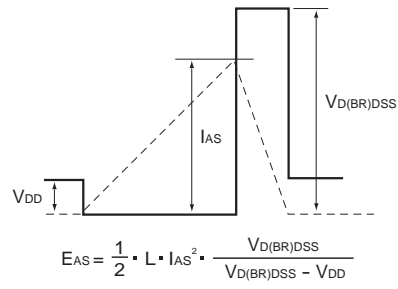


Fig.3-2 Avalanche waveform

Notes

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